IN

OFFSET 2N1

- No Frequency Compensation Required
- Low Power Consumption
- Short-Circuit Protection
- Offset-Voltage Null Capability
- Wide Common-Mode and Differential Voltage Ranges
- No Latch-Up
- Designed to Be Interchangeable With Fairchild μA747C and μA747M

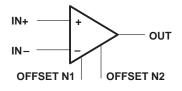
description

The uA747 is a dual general-purpose operational amplifier featuring offset-voltage null capability. Each half is electrically similar to uA741.

The high common-mode input voltage range and the absence of latch-up make this amplifier ideal for voltage-follower applications. The device is short-circuit protected and the internal frequency compensation ensures stability without external components. A low-value potentiometer may be connected between the offset null inputs to null out the offset voltage as shown in Figure 2.

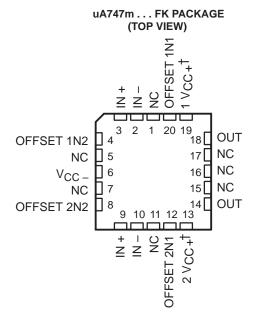
The uA747C is characterized for operation from 0° C to 70° C; the uA747M is characterized for operation over the full military temperature range of -55° C to 125° C.

symbol (each amplifier)



(TOP VIEW) 14 OFFSET 1N1 IN + [] 1 V_{CC +}† 2 13 OFFSET 1N2 □ Тυο Π 12 J NC Vcc_[11 10 OUT IN + [9 2 V_{CC+}†

D, J, N, OR W PACKAGE



NC - No internal connection

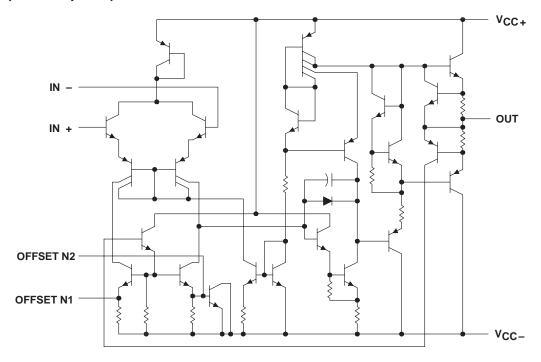
AVAILABLE OPTIONS

		PACKAGE							
	V _{IO} Max AT 25°C		20-PIN						
TA		SMALL OUTLINE (D)	CERAMIC DIP (J)	PLASTIC DIP (N)	FLAT PACK (W)	CHIP CARRIER (FK)			
0°C to 70°C	6 mV	uA747CD	_	uA747CN	_	_			
−55°C to 125°C	5 mV	_	uA747MJ	_	uA747MW	uA747MFK			

The D package is available taped and reeled. Add the suffix R to the device type, (i.e., uA747CDR).

[†] The two positive supply terminals (1 V_{CC +} and 2 V_{CC +}) are connected together internally.

schematic (each amplifier)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

		uA747C	uA747M	UNIT		
Supply voltage, V _{CC+} (see Note 1)		18	22	V		
Supply voltage, V _{CC} (see Note 1)		-18	-22	V		
Differential input voltage (see Note 2)			±30	V		
Input voltage any input (see Notes 1 and 3)		±15 ±15 V				
Voltage between any offset null terminal (N1/N2) and V _{CC} -	±0.5	±0.5	V			
Duration of output short circuit (see Note 4)			unlimited			
Continuous total dissipation	See Dissipation Rating Table					
Operating free-air temperature range	0 to 70	-55 to 125	°C			
Storage temperature range	-65 to 150	-65 to 150	°C			
Case temperature for 60 seconds	FK package		260	°C		
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	J or W package		300	°C		
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D or N package	260		°C		

- NOTES: 1. All voltage values, unless otherwise noted, are with respect to the midpoint between V_{CC} + and V_{CC} -.
 - 2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.
 - 3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.
 - 4. The output may be shorted to ground or either power supply. For the uA747M only, the unlimited duration of the short circuit applies at (or below) 125°C case temperature or 75°C free-air temperature.

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{\scriptsize A}} \leq 25^{\circ}\mbox{\scriptsize C}$ POWER RATING	DERATING FACTOR	DERATE ABOVE T _A	T _A = 70°C POWER RATING	T _A = 125°C POWER RATING
D	800 mW	7.6 mW/°C	45°C	608 mW	_
FK	800 mW	11.0 mW/°C	77°C	800 mW	275 mW
J	800 mW	11.0 mW/°C	77°C	800 mW	275 mW
N	800 mW	9.2 mW/°C	63°C	736 mW	_
W	800 mW	8.0 mW/°C	50°C	640 mW	200 mW



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electrical characteristics at specified free-air temperature, $V_{\mbox{CC}\pm}$ = $\pm 15~\mbox{V}$

	DADAMETED	TEST CONDITIONS [†]	т. т	uA747C			uA747M			LINUT	
	PARAMETER	TEST CONDITIONS†	TA [∓]	MIN	TYP	MAX	MIN	TYP	MAX	UNIT	
\/. -	Innut offeet velters	V- 0	25°C		1	6		1	5	>/	
VIO	Input offset voltage	VO = 0	Full range			7.5			6	mV	
^{ΔV} IO(adj)	Offset voltage adjust range		25°C		±15			±15		mV	
lu a			25°C		20	200		20	200	nA	
IIO	Input offset current		Full range			300			500		
1	Input high ourrent		25°C		80	500		80	500	nΛ	
IIB	Input bias current		Full range			800			1500	nA	
\/	Common-mode		25°C	±12	±13		±12	±13		V	
VICR	input voltage range		Full range	±12			±12			V	
	Maximum peak-to-peak	R _L = 10 kΩ	25°C	24	28		24	28		V	
V		R _L ≥ 10 kΩ	Full range	24			24				
VO(PP)	output voltage swing	R _L = 2 kΩ	25°C	20	26		20	26			
		$R_L \ge 2 k\Omega$	Full range	20			20				
Δ.	Large-signal differential	$R_L \ge 2 k\Omega$,	25°C	25	200		50	200		V/mV	
AVD	voltage amplification	$V_0 = \pm 10 \text{ V}$	Full range	15			25				
rį	Input resistance		25°C	0.3	2		0.3*	2		MΩ	
r _O	Output resistance	See Note 5	25°C		75			75		Ω	
Ci	Input capacitance		25°C		1.4			1.4		pF	
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICR}	25°C	70	90		70	90		dB	
CMRR			Full range	70			70				
ksvs	Supply-voltage sensitivity	V _{CC} = ± 9 V to ± 15 V	25°C Full range		30	150		30	150	μV/V	
	(ΔV _{IO} / ΔV _{CC})					150			150	μ	
los	Short-circuit output current		25°C		±25	±40		±25	±40	mA	
la a	Supply current (each amplifier)	No load	25°C		1.7	2.8		1.7	2.8	mA	
ICC			Full range			3.3			3.3		
PD	Power dissipation	No load, $V_0 = 0$	25°C		50	85		50	85	mW	
' טי	(each amplifier)	140 loau, VO = 0	Full range			100			100		
V_{01}/V_{02}	Channel separation		25°C		120			120	0	dB	

[†] All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified.

operating characteristics, V_{CC \pm} = \pm 15 V, T_A = 25°C

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _r	Rise time	$V_1 = 20 \text{ mV}, R_1 = 2 \text{ k}\Omega, C_1 = 100 \text{ pF}, \text{ See Figure 1}$		0.3		μs
	Overshoot factor	V = 20 111V, KL = 2 KΩ, CL = 100 pr, See Figure 1		5%		
SR	Slew rate at unity gain	$V_I = 10 \text{ mV}, R_L = 2 \text{ k}\Omega, C_L = 100 \text{ pF}, \text{ See Figure 1}$		0.5		V/μs

[‡] Full range for uA747C is 0°C to 70°C and for uA747M is -55°C to 125°C.

^{*}On products compliant to MIL-STD-883, Class B, this parameter is not production tested.

NOTE 5: This typical value applies only at frequencies above a few hundred hertz because of the effects of drift and thermal feedback.

PARAMETER MEASUREMENT INFORMATION

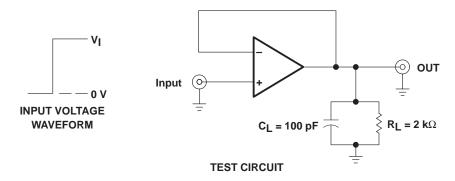


Figure 1. Rise Time, Overshoot, and Slew Rate

APPLICATION INFORMATION

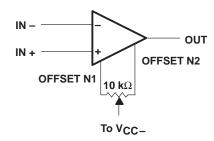


Figure 2. Input Offset Voltage Null Circuit

TYPICAL CHARACTERISTICS[†]

INPUT OFFSET CURRENT vs

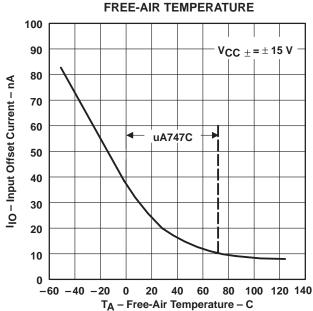


Figure 3

INPUT BIAS CURRENT

vs FREE-AIR TEMPERATURE

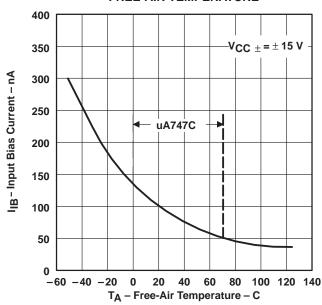


Figure 4

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature range of the particular devices.



TYPICAL CHARACTERISTICS

8

4 0

100

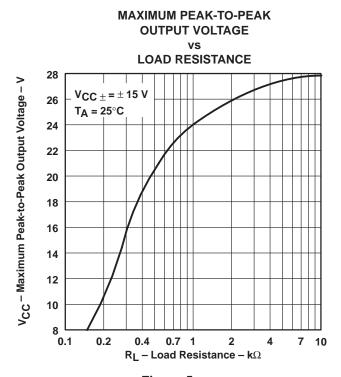


Figure 5

OPEN-LOOP LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION

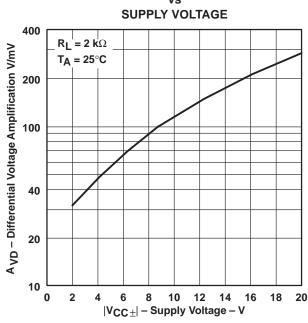


Figure 7

OUTPUT VOLTAGE FREQUENCY 40 VO(PP) - Maximum Peak-to-Peak Output Voltage - V V_{CC±} = ± 15 V 36 $R_L = 10 \text{ k}\Omega$ $T_A = 25^{\circ}\text{C}$ 32 28 24 20 16 12

MAXIMUM PEAK-TO-PEAK

Figure 6

OPEN-LOOP LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION

10 k

f - Frequency - Hz

100 k

1 M

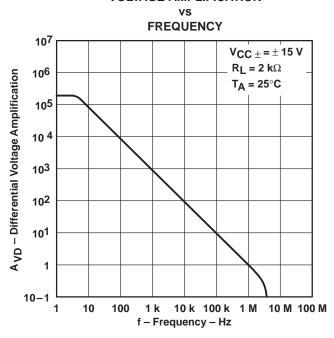


Figure 8



TYPICAL CHARACTERISTICS

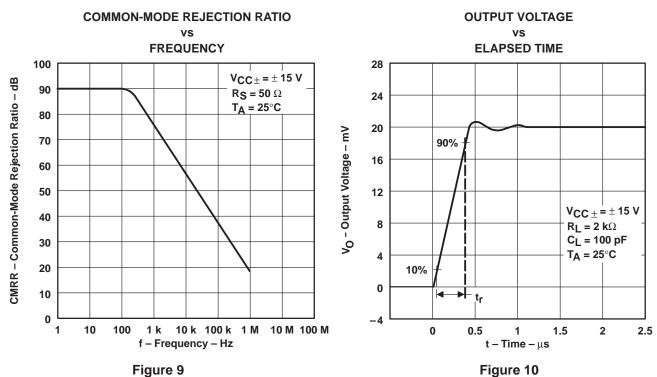
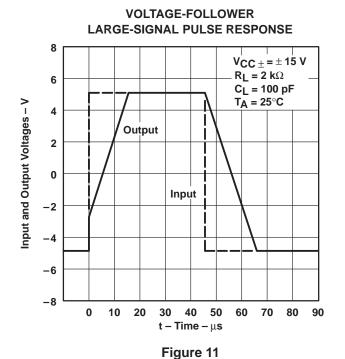


Figure 9



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